

## GN8061

## GaAs IC

For semiconductor laser drive

## ■ Features

- High-speed switching
- High output
- Pulse current and DC bias current can be controlled.

## ■ Absolute Maximum Ratings (Ta = 25°C)

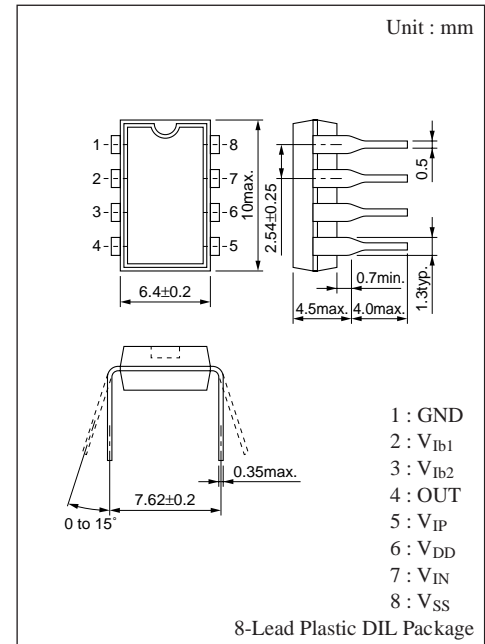
Parameter	Symbol	Rating	Unit
Power supply voltage	V <sub>DD</sub>	6	V
	V <sub>SS</sub>	-6	V
Pin voltage	V <sub>Ib1</sub> *1	6	V
	V <sub>Ib2</sub>	0.5	V
	V <sub>IN</sub>	-0.5 to V <sub>DD</sub> -1.5	V
	V <sub>IP</sub> *5	1.5 to 6	V
	V <sub>OUT</sub> *1	6	V
Power current	I <sub>DD</sub> *4	55	mA
	I <sub>SS</sub>	40	mA
Output current	I <sub>OUT</sub>	225	mA
Allowable power dissipation	P <sub>D</sub> *2	700	mW
Channel temperature	T <sub>ch</sub>	150	°C
Storage temperature	T <sub>stg</sub>	-55 to +150	°C
Operating ambient temperature	T <sub>opr</sub> *3	-10 to +75	°C

- \*1 Do not apply the voltage higher than the set V<sub>DD</sub>.  
 \*2 Guaranteed for the unit in the natural atmosphere.  
 \*3 IC circuit functioning range. Note however that the electrical characteristics shown at Ta= 25°C is not guaranteed.  
 \*4 I<sub>DD</sub> is a current when the pulse output current and bias output current are zero.  
 \*5 Voltage when the constant current source has been connected.

## ■ Electrical Characteristics (Ta = 25°C)

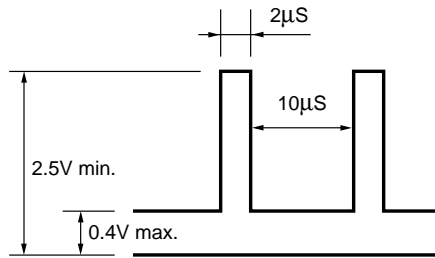
Parameter	Symbol	Test circuit	Condition	Min	Typ	Max	Unit
Pulse output current	I <sub>pmax.</sub>	1	V <sub>IN</sub> = 2.0V, V <sub>Ib2</sub> = -5V	100	120		mA
	I <sub>pmin.</sub>	1	V <sub>IN</sub> = 0.4V, V <sub>Ib2</sub> = -5V		1	5	mA
Bias output current	I <sub>bmax.</sub>	2	I <sub>P</sub> = 0, V <sub>Ib1</sub> = 5V, V <sub>Ib2</sub> = 0	80	100		mA
	I <sub>bmin.1</sub>	2	I <sub>P</sub> = 0, V <sub>Ib1</sub> = 0, V <sub>Ib2</sub> = 0		1	5	mA
	I <sub>bmin.2</sub>	2	I <sub>P</sub> = 0, V <sub>Ib1</sub> = 5V, V <sub>Ib2</sub> = -5V		0.05	0.1	mA
Supply current	I <sub>DD</sub> *1	2	V <sub>Ib1</sub> = 5V, V <sub>Ib2</sub> = -5V, V <sub>IN</sub> = 0.4V		35	55	mA
	I <sub>SS</sub>	2	I <sub>P</sub> = 0		25	40	mA
Input voltage	V <sub>IH</sub>			2.5			V
	V <sub>IL</sub>					0.4	V
Rise time	t <sub>r</sub> *2	3	V <sub>Ib1</sub> = 0, V <sub>Ib2</sub> = -5V, I <sub>P</sub> =100mA			7	ns
Fall time	t <sub>f</sub> *2	3				5	ns

Note : Following condition is applied unless otherwise specified: V<sub>DD</sub>= 5V, V<sub>SS</sub>= -5V, V<sub>Ib1</sub>= 0V, V<sub>Ib2</sub>= 0V  
 Set the supply current of constant current source to I<sub>P</sub>=120mA and load resistance to R<sub>L</sub>=10Ω



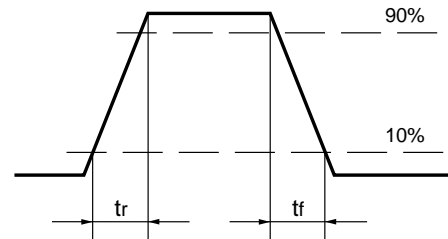
- \* 1 The current value to be supplied from the 5V power supply is a total sum of this value plus the pulse output current and bias output current.
- \* 2 Waveform of input and output signals

Input signal



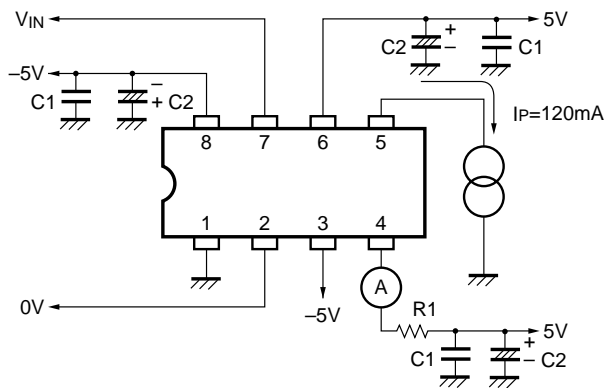
\* The rise/fall time of the input signal is 2ns (10 to 90%)

Output waveform

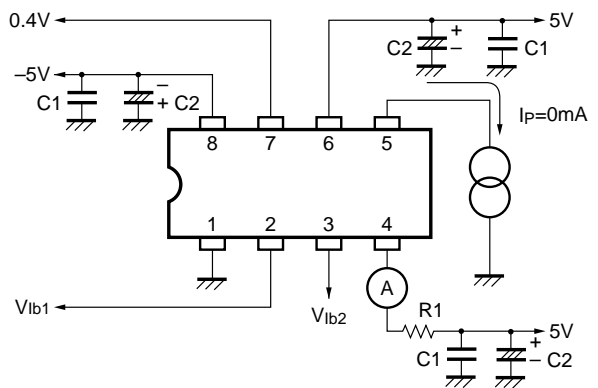


$t_r \dots 10\% \text{ to } 90\%$   
 $t_f \dots 90\% \text{ to } 10\%$

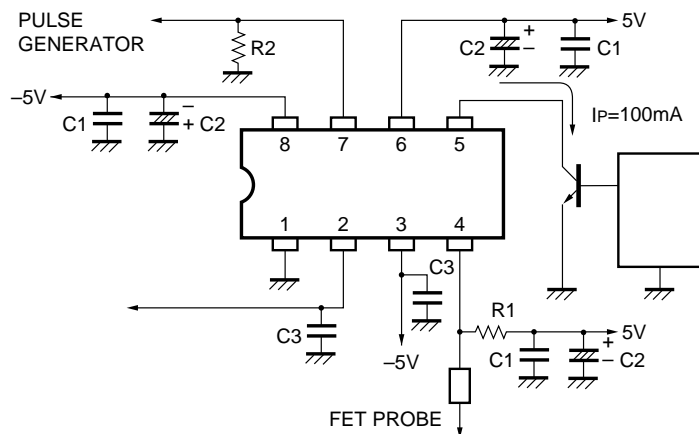
Test circuit 1



Test circuit 2

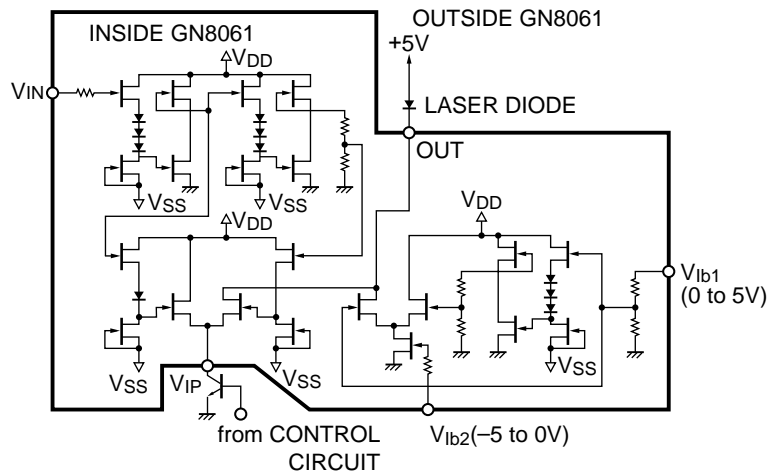


Test circuit 3



- $C_1 : 0.1\mu\text{F}$
- $C_2 : 3.3\mu\text{F}$
- $C_3 : 2200\text{pF}$
- $R_1 : 10\Omega$
- $R_2 : 50\Omega$

## ■ Block Diagram



## ■ Caution for Handling

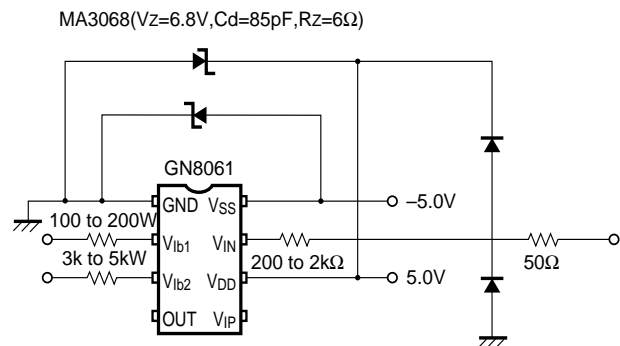
- 1) The recommended  $V_{IN}$  voltage is 2.5 to 3V for [H] and 0 to 0.4V for [L].
- 2) Do not apply  $V_{IN}$  while the power supply is OFF.
- 3) For the current source to be connected to the  $V_{IP}$  pin, use a Si bipolar transistor as shown in the circuit diagram.

(Example: 2SD874)

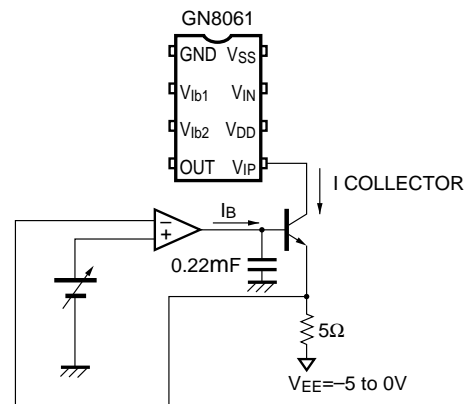
To connect a resistor to the emitter or collector, use a resistor of a few ohm. The use of higher resistor may cause large change in the voltage at the  $V_{IP}$  pin, and may make the output waveform distortion. (See the pulse output current control example).

To use another current control circuit, set so that the  $V_{IP}$  pin voltage becomes around 2V.

- 4) When mounting, minimize the connection distance between the semiconductor laser and IC, and use the chip parts (C, R) of less parasitic effects.
- 5) Attention to damage by the power surge (see the example connection of the pin protection circuit). During handling, take care to ground the human body and solder iron tip.
- 6) The current value of the current source connected to the  $V_{IP}$  pin should be zero to protect the semiconductor laser when the power supply is turned ON and OFF. When the power supply is ON, make  $V_{SS}$  to rise earlier than  $V_{DD}$ . When the power supply is OFF, make  $V_{DD}$  to fall earlier than  $V_{SS}$ . When  $V_{DD}=5V$ ,  $V_{SS}=0$  even transitional, the current of about 30mA flows through the semiconductor laser.
- 7) Pay attention to release the heat.

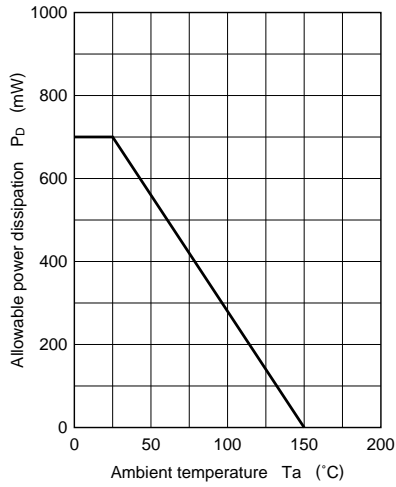


Connection example of pin protection circuit

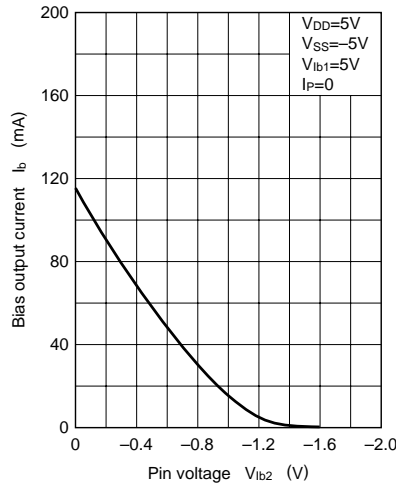


Example of pulse output current control circuit

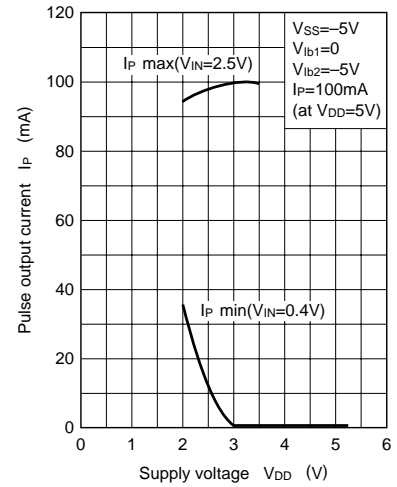
$P_D - T_a$



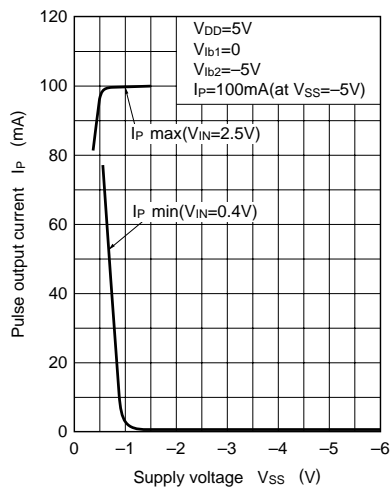
$I_b - V_{Ib2}$



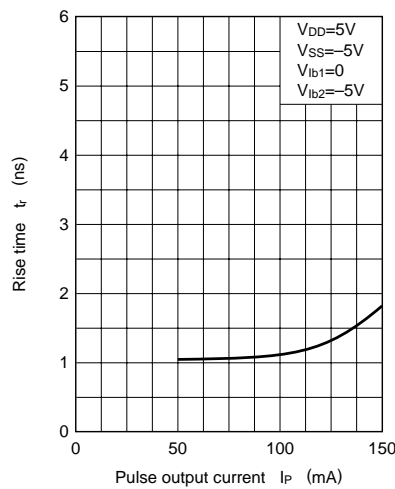
$I_P - V_{DD}$



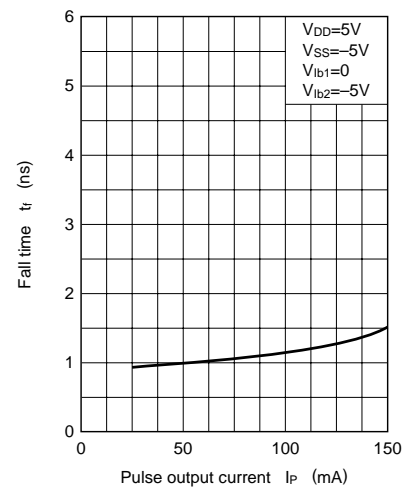
$I_P - V_{SS}$



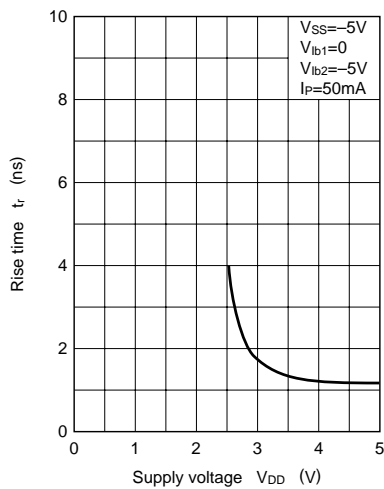
$t_r - I_P$



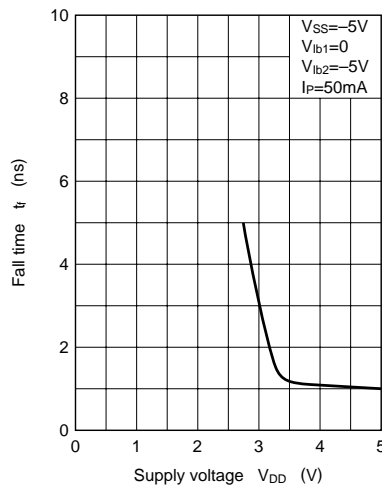
$t_f - I_P$



$t_r - V_{DD}$



$t_f - V_{DD}$



$t_r - V_{SS}$

